

HD74ALVC16244

16-bit Buffer / Driver with 3-state Outputs

HITACHI

ADE-205-206 (Z)
Preliminary
1st. Edition
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Description

This 16-bit buffer / driver is designed for 2.3 V to 3.6 V V_{CC} operation.

The HD74ALVC16244 is designed specifically to improve the performance and density of 3-state memory address drivers, clock drivers, and bus oriented receivers and transmitters. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer. It provides true outputs and symmetrical active-low output-enable (\overline{OE}) inputs.

To ensure the high impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current sinking capability of the driver.

Features

- $V_{CC} = 2.3$ V to 3.6 V
- Typical V_{OL} ground bounce < 0.8 V (@ $V_{CC} = 3.3$ V, $T_a = 25^\circ C$)
- Typical V_{OH} undershoot > 2.0 V (@ $V_{CC} = 3.3$ V, $T_a = 25^\circ C$)
- High output current ± 24 mA (@ $V_{CC} = 3.0$ V)

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Function Table

Inputs		Output Y
OE	A	
L	H	H
L	L	L
H	X	Z

H : High level

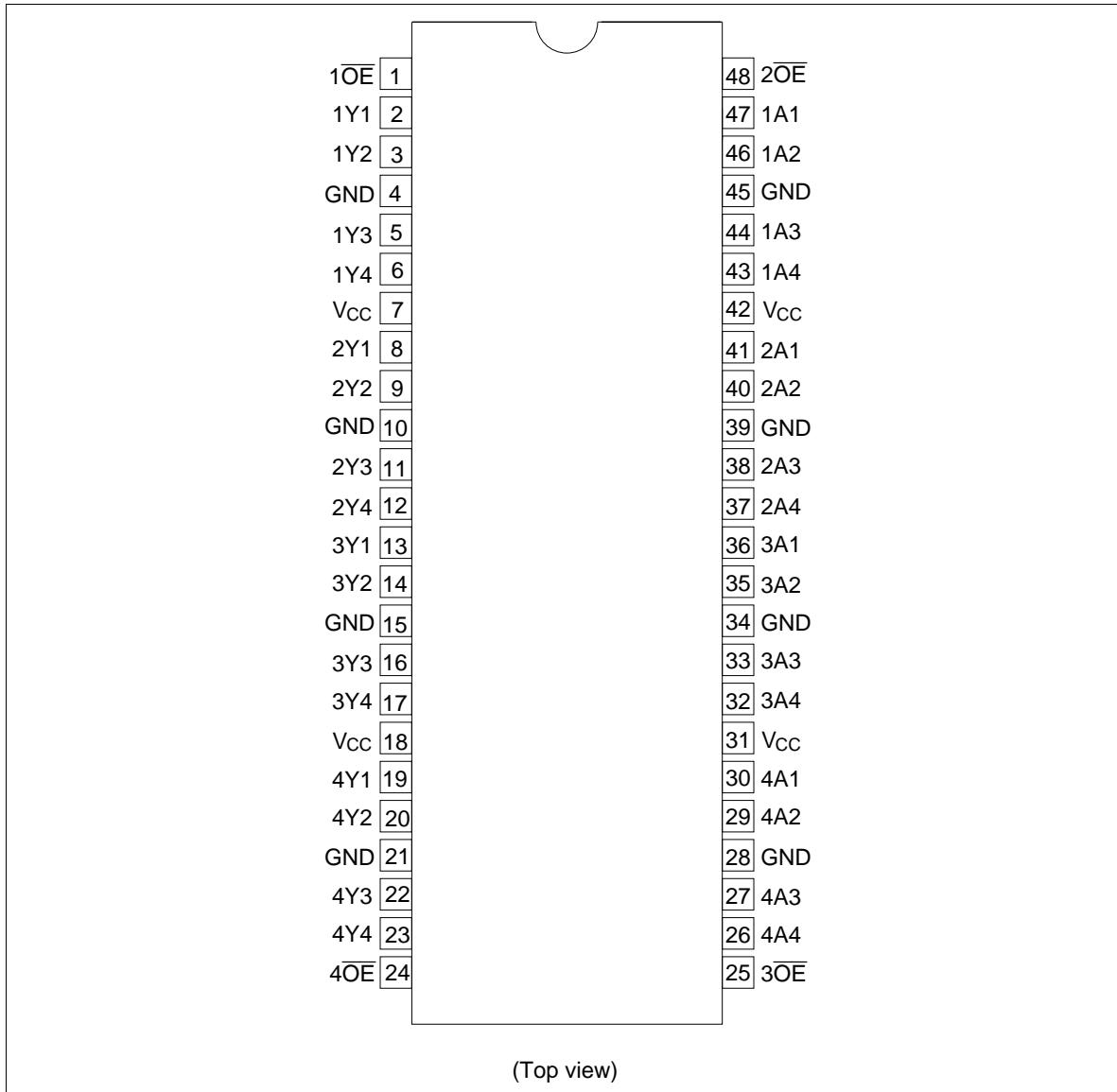
L : Low level

X : Immaterial

Z : High impedance

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Pin Arrangement



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Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	−0.5 to 4.6	V	
Input voltage ¹	V_I	−0.5 to 4.6	V	
Output voltage ^{1,2}	V_O	−0.5 to V_{CC} +0.5	V	
Input clamp current	I_{IK}	−50	mA	$V_I < 0$
Output clamp current	I_{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I_O	±50	mA	$V_O = 0$ to V_{CC}
V_{CC} , GND current / pin	I_{CC} or I_{GND}	±100	mA	
Maximum power dissipation at $T_a = 55^\circ C$ (in still air) ³	P_T	0.85	W	TSSOP
Storage temperature	T_{STG}	−65 to 150	°C	

Notes: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

1. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.
2. This value is limited to 4.6 V maximum.
3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.

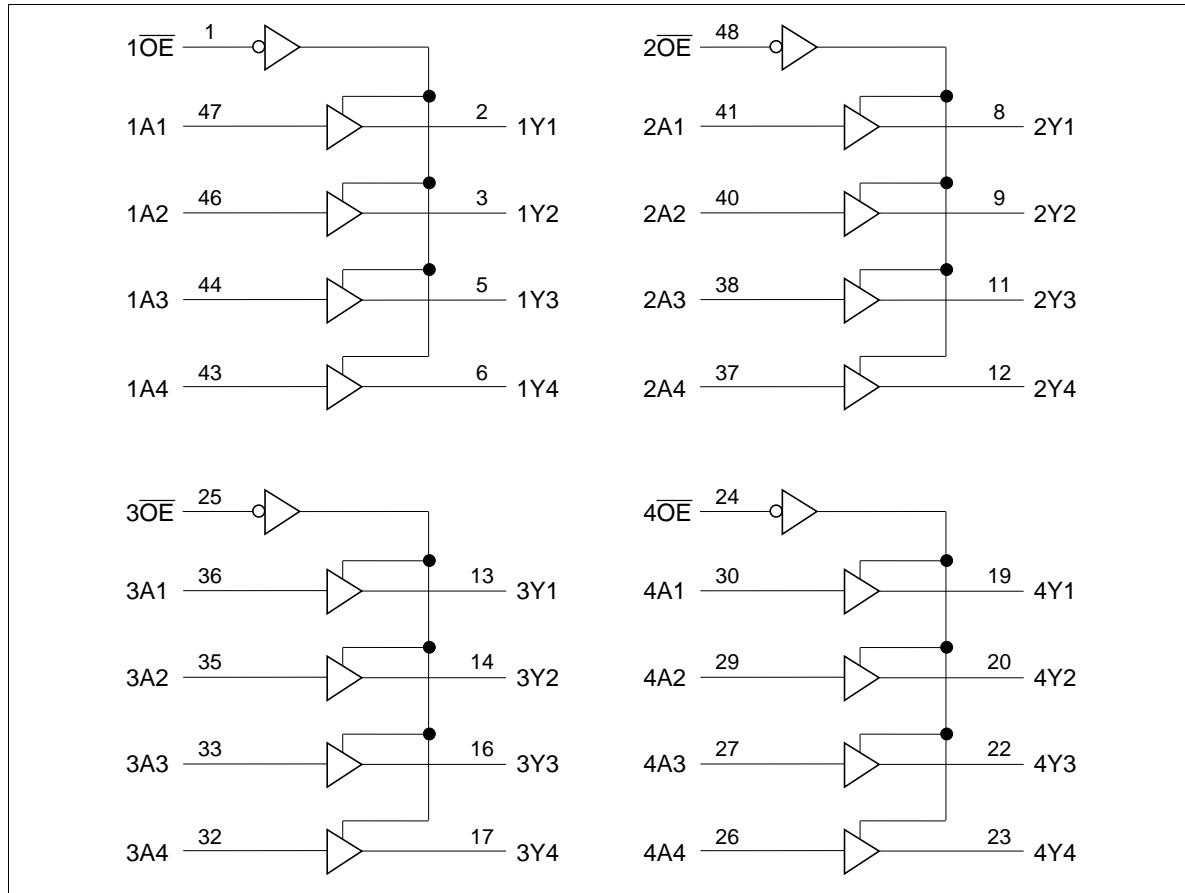
Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage	V_{CC}	2.3	3.6	V	
Input voltage	V_I	0	V_{CC}	V	
Output voltage	V_O	0	V_{CC}	V	
High level output current	I_{OH}	—	−12	mA	$V_{CC} = 2.3$ V
		—	−12		$V_{CC} = 2.7$ V
		—	−24		$V_{CC} = 3.0$ V
Low level output current	I_{OL}	—	12	mA	$V_{CC} = 2.3$ V
		—	12		$V_{CC} = 2.7$ V
		—	24		$V_{CC} = 3.0$ V
Input transition rise or fall rate	$\Delta t / \Delta v$	0	10	ns / V	
Operating temperature	T_a	−40	85	°C	

Note: Unused control inputs must be held high or low to prevent them from floating.

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Logic Diagram



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Electrical Characteristics (Ta = -40 to 85°C)

	Symbol	V _{cc} (V)	Min	Max	Unit	Test Conditions
Input voltage	V _{IH}	2.3 to 2.7	1.7	—	V	
		2.7 to 3.6	2.0	—		
	V _{IL}	2.3 to 2.7	—	0.7		
		2.7 to 3.6	—	0.8		
Output voltage	V _{OH}	2.3 to 3.6	V _{cc} - 0.2	—	V	I _{OH} = -100 µA
		2.3	2.0	—		I _{OH} = -6 mA, V _{IH} = 1.7 V
		2.3	1.7	—		I _{OH} = -12 mA, V _{IH} = 1.7 V
		2.7	2.2	—		I _{OH} = -12 mA, V _{IH} = 2.0 V
		3.0	2.4	—		I _{OH} = -12 mA, V _{IH} = 2.0 V
		3.0	2.0	—		I _{OH} = -24 mA, V _{IH} = 2.0 V
	V _{OL}	2.3 to 3.6	—	0.2		I _{OL} = 100 µA
		2.3	—	0.4		I _{OL} = 6 mA, V _{IL} = 0.7 V
		2.3	—	0.7		I _{OL} = 12 mA, V _{IL} = 0.7 V
		2.7	—	0.4		I _{OL} = 12 mA, V _{IL} = 0.8 V
		3.0	—	0.55		I _{OL} = 24 mA, V _{IL} = 0.8 V
Input current	I _{IN}	3.6	—	±5	µA	V _{IN} = V _{cc} or GND
Off state output current	I _{OZ}	3.6	—	±10	µA	V _{OUT} = V _{cc} or GND
Quiescent supply current	I _{CC}	3.6	—	40	µA	V _{IN} = V _{cc} or GND
	ΔI _{CC}	3.0 to 3.6	—	750	µA	V _{IN} = one input at (V _{cc} - 0.6) V, other inputs at V _{cc} or GND

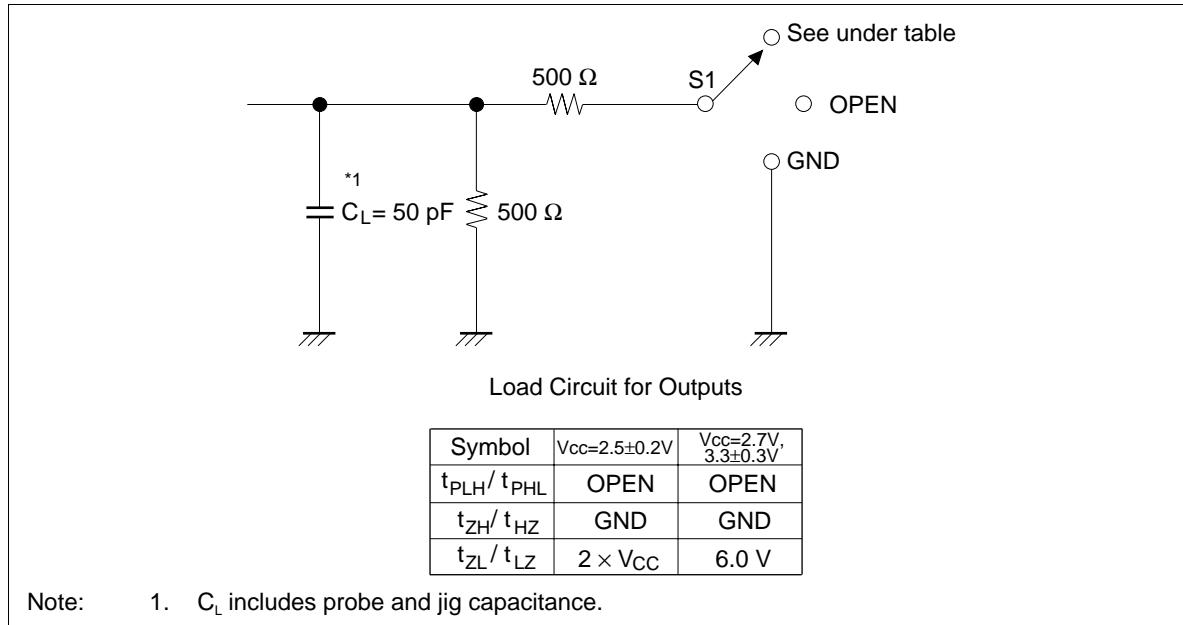
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Switching Characteristics (Ta = -40 to 85°C)

Item	Symbol	V _{cc} (V)	Min	Typ	Max	Unit	FROM (Input)	TO (Output)
Propagation delay time	t_{PLH}	2.5±0.2	1.0	—	3.7	ns	A	Y
	t_{PHL}	2.7	—	—	3.6			
		3.3±0.3	1.0	—	3.0			
Output enable time	t_{ZH}	2.5±0.2	1.0	—	5.7	ns	\overline{OE}	Y
	t_{ZL}	2.7	—	—	5.4			
		3.3±0.3	1.0	—	4.4			
Output disable time	t_{HZ}	2.5±0.2	1.0	—	5.2	ns	\overline{OE}	Y
	t_{LZ}	2.7	—	—	4.6			
		3.3±0.3	1.0	—	4.1			
Input capacitance	C_{IN}	3.3	—	3.0	—	pF	Control inputs	
		3.3	—	6.0	—		Data inputs	
Output capacitance	C_o	3.3	—	7.0	—	pF	Outputs	

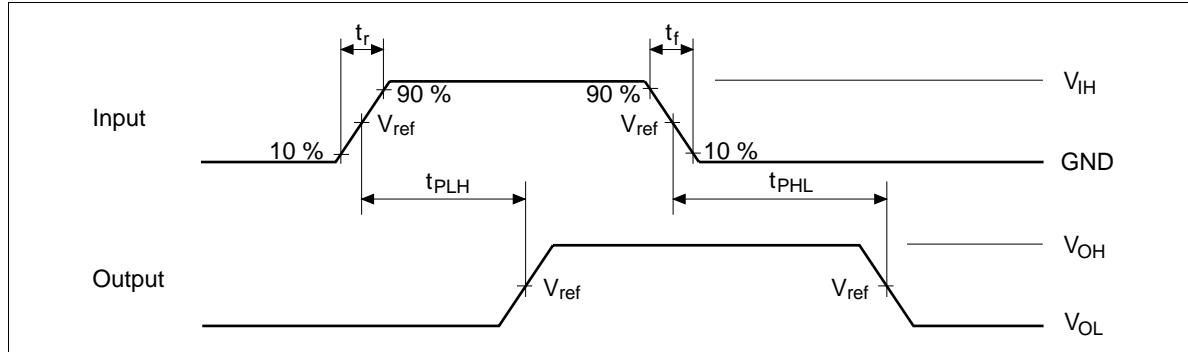
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Test Circuit

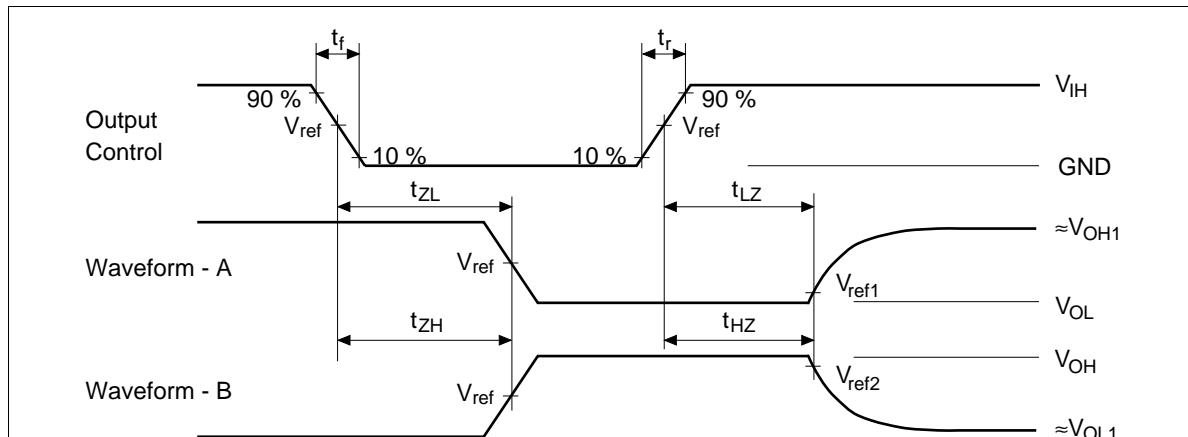


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Waveforms – 1



Waveforms – 2



TEST	$V_{CC} = 2.5 \pm 0.2 V$	$V_{CC} = 2.7 V, 3.3 \pm 0.3 V$
V_{IH}	V_{CC}	2.7 V
V_{ref}	$1/2 V_{CC}$	1.5 V
V_{ref1}	$V_{OL} + 0.15 V$	$V_{OL} + 0.3 V$
V_{ref2}	$V_{OH} - 0.15 V$	$V_{OH} - 0.3 V$
V_{OH1}	V_{CC}	3.0 V
V_{OL1}	GND	GND

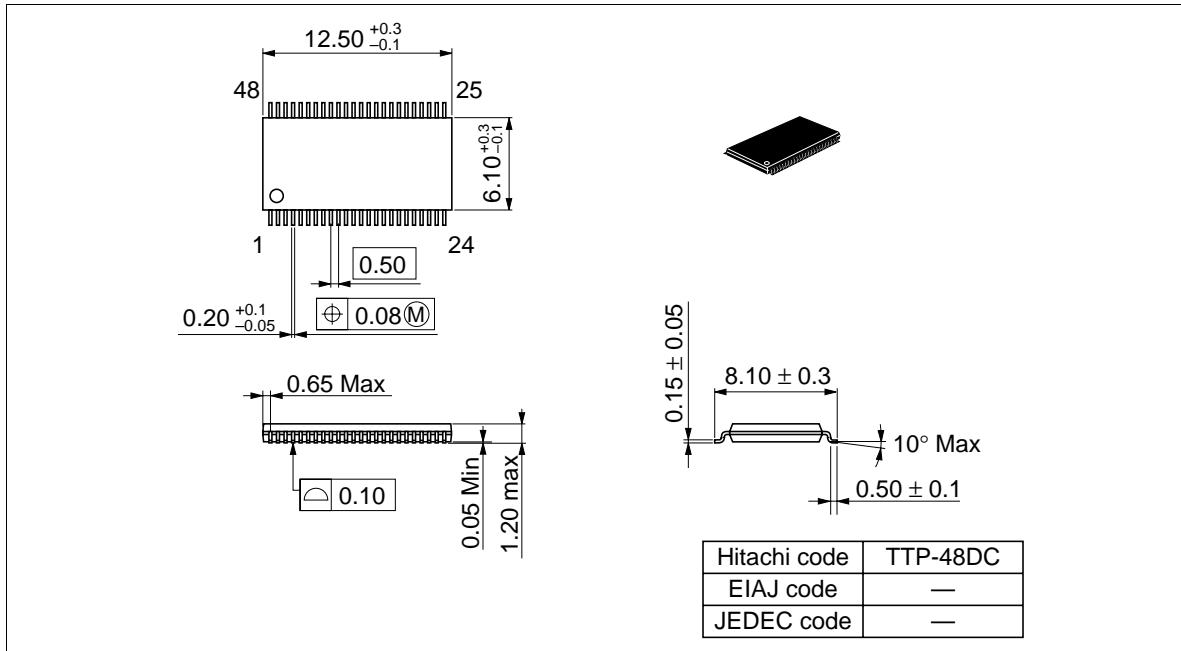
Notes:

1. All input pulses are supplied by generators having the following characteristics :
 $PRR \leq 10 \text{ MHz}$, $Z_o = 50 \Omega$, $t_r \leq 2.0 \text{ ns}$, $t_f \leq 2.0 \text{ ns}$. ($V_{CC} = 2.5 \pm 0.2 \text{ V}$)
 $PRR \leq 10 \text{ MHz}$, $Z_o = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$. ($V_{CC} = 2.7 \text{ V}, 3.3 \pm 0.3 \text{ V}$)
2. Waveform – A is for an output with internal conditions such that the output is low except when disabled by the output control.
3. Waveform – B is for an output with internal conditions such that the output is high except when disabled by the output control.
4. The output are measured one at a time with one transition per measurement.

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Package Dimensions

Unit : mm



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Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan

Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose, CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223	Hitachi Europe GmbH Electronic components Group Dornacher Straße 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0 Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322	Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533 Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building, No.167, Tun-Hwa North Road, Taipei (105) Maidenhead Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322	Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX
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